

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of: **Shigeki ITO et al.**

Serial Number: **Not yet assigned**

(§371 of international application No. PCT/JP2004/014282)

Filed: **March 22, 2006**

For: **ANTISTATIC GLASS SUBSTRATE PRODUCTION METHOD AND
ANTISTATIC GLASS SUBSTRATE PRODUCED BY THE METHOD**

Attorney Docket Number: **062258**

Customer Number: **38834**

INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents
P. O. Box 1450
Alexandria, VA 22313-1450

March 22, 2006

Sir:

In compliance with 37 C.F.R. §1.56, Applicants direct the attention of the Patent and Trademark Office to the documents listed on the attached PTO/SB/08. A copy of each non- U.S. document is enclosed herewith as well as an International Search Report mailed January 11, 2005.

If there are any fees due in connection with the filing of this paper, please charge Deposit Account No. 50-2866.

Respectfully submitted,

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Enclosure: PTO/SB/08, Documents (5) & Int'l Search Report

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| Combined Form PTO/SB/08A&B | | | | Complete if Known | |
| INFORMATION DISCLOSURE STATEMENT BY APPLICANT <i>(use as many sheets as necessary)</i> | | | | Application Number | Not yet assigned |
| | | | | Confirmation Number | |
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| | | | | First Named Inventor | Shigeki ITO et al. |
| | | | | Art Unit | |
| | | | | Examiner Name | |
| Sheet | 1 | of | 1 | Attorney Docket Number | 062258 |

U.S. PATENT DOCUMENTS

| Examiner Initials* | Cite No. ¹ | Document Number | | Publication Date MM-DD-YYYY | Name of Patentee or Applicant of Cited Document |
|--------------------|-----------------------|-----------------|--------------------------------------|--------------------------------|---|
| | | Number | Kind Code ² (if known) | | |
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FOREIGN PATENT DOCUMENTS

| Examiner Initials* | Cite No. ¹ | Foreign Patent Document | | | Publication Date MM-DD-YYYY | Name of Patentee or Applicant of Cited Document | Translation ⁴ |
|--------------------|-----------------------|---------------------------|---------------------|--------------------------------------|--------------------------------|---|--------------------------|
| | | Country Code ³ | Number ⁴ | Kind Code ² (if known) | | | |
| | 1 | JP | 2002-93768 | | 3/29/2002 | Matsushita Electric Works Ltd | Abstract |
| | 2 | JP | 2-74901 | | 3/14/1990 | Fukui Pref Gov | Abstract |
| | 3 | JP | 6-219868 | | 8/9/1994 | Bayer AG | Abstract |
| | 4 | JP | 2002-72922 | | 3/12/2002 | Asahi Glass Co Ltd | Abstract |
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NON PATENT LITERATURE DOCUMENTS

| Examiner Initials* | Cite No. ¹ | Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city, and/or country where published. | Translation ⁴ |
|--------------------|-----------------------|--|--------------------------|
| | 5 | HARUHISA FUJII, "Control of Charge on Insulating Glass in Vacuum by Plasma Processing", IEEE Transaction on Dielectrics and Electrical Insulation 2002, Vol. 9, No. 2, pages 230-235 | |
| | 6 | International Search Report of International Application PCT/JP2004/014282 mailed January 11, 2005 | |
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| Examiner Signature | /Lauren Robinson/ | Date Considered | 11/24/2008 |
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*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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